



80V NPN MEDIUM POWER TRANSISTOR IN TO126

Features

- BV_{CEO} > 80V
- I_C = 1A Continuous Collector Current
- I_{CM} = 2A Peak Pulse Current
- Low Saturation Voltage V_{CE(sat)} < 500mV @ 0.5A
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: TO126
- Case Material: Molded Plastic, "Green" Molding Compound;
 UL Flammability Classification Rating 94V-0
- Terminals: Matte Tin Finish; Solderable per MIL-STD-202, Method 208 ³
- Weight: TO126: 400mg (Approximate)

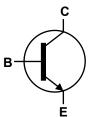
Applications

- Medium Power Switching or Amplification Applications
- AF driver and output stages

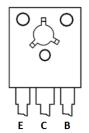
TO126



Top View



Equivalent Circuit



Front Face View Pin-Out

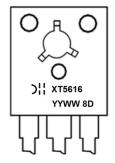
Ordering Information (Note 4)

Product	Package	Marking	Quantity
DXT5616U	TO126	XT5616	1,690 per box in tubes (65 per tube)

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



XT5616 = Product type marking code Date Code Format = YYWW

YY = Last two digits of Year(ex 14=2014)

WW = Week (01-53)

8D = Assembly and Foundry code





Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Collector-Base Voltage	V _{CBO}	100	V	
Collector-Emitter Voltage	V _{CEO}	80	V	
Emitter-Base Voltage	V _{EBO}	5	V	
Continuous Collector Current	Ic	1	Δ.	
Peak Pulse Collector Current	I _{CM}	2		
Continuous Base Current	I _B	100	mΛ	
Peak Pulse Base Current	I _{BM}	200	mA mA	

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Dower Dissipation	(Note 5)	Б.	1.3	w	
Power Dissipation	(Note 6) $T_L = +25^{\circ}C$		20	VV	
Thermal Resistance, Junction to Ambient	(Note 5)	$R_{\theta JA}$	96	°C/W	
Thermal Resistance, Junction to Lead	(Note 6)	R _{0JL}	6.25	°C/W	
Operating and Storage Temperature Range		T _{J,} T _{STG}	-65 to +150	°C	

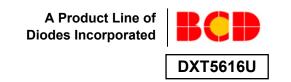
ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

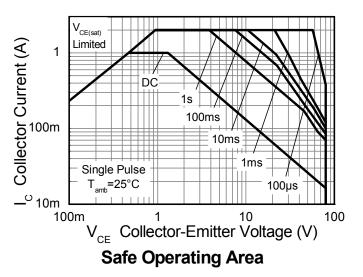
Notes:

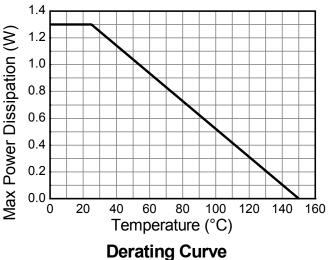
- For a through-hole device mounted on minimum recommended pad layout with 10mm lead length from the bottom of package to the board that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
 Thermal resistance from junction to solder-point at the seating plane (2.5mm from the bottom of package along the collector lead).
 Refer to JEDEC specification JESD22-A114 and JESD22-A115.

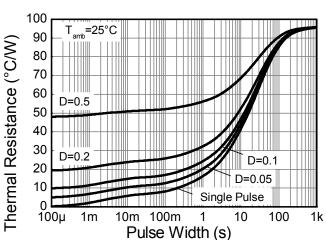


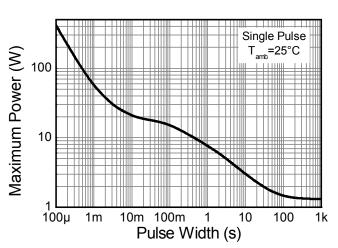


Thermal Characteristics and Derating Information









Transient Thermal Impedance

Pulse Power Dissipation

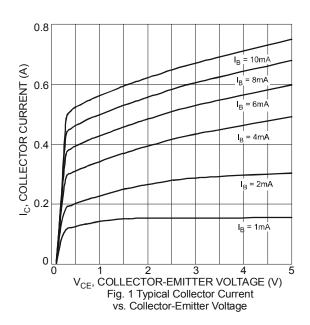


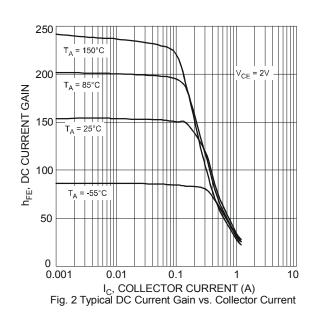
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Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	100	_	-	٧	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 6)	BV _{CEO}	80		1	V	I _C = 10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	7	1	1	V	I _E = 100μA
Collector Cut-off Current	I _{CBO}	1	1	0.1 20	μΑ	V _{CB} = 80V V _{CB} = 80V, T _A = +150°C
Emitter Cut-off Current	I _{EBO}	1	-	20	nA	V _{EB} = 6V
Static Forward Current Transfer Ratio (Note 6)	h _{FE}	25 100 25		_ 250 _		$I_C = 5mA, V_{CE} = 2V$ $I_C = 150mA, V_{CE} = 2V$ $I_C = 500mA, V_{CE} = 2V$
Collector-Emitter Saturation Voltage (Note 6)	V _{CE(sat)}	-	_	0.5	V	I _C = 500mA, I _B = 50mA
Base-Emitter Turn-On Voltage (Note 6)	V _{BE(on)}	-	_	1.0	V	$I_C = 500 \text{mA}, V_{CE} = 2V$
Transition Frequency	f⊤	150	_	_	MHz	I _C = 50mA, V _{CE} = 10V f = 100MHz
Output Capacitance	Cobo	1	ı	25	pF	V _{CB} = 10V, f = 1MHz
Delay Time	t _d	-	21	_		
Rise Time	t _r	1	33	_	20	I _C = 400mA, V _{CC} = 40V,
Storage Time with Resistive Load	ts	_	708	_	ns	$I_{B1} = 20 \text{mA}, I_{B2} = -20 \text{mA}$
Fall Time with Resistive Load	t _f	_	95	_		

Notes: 6. Measured under pulsed conditions. Pulse width $\leq 300 \mu s$. Duty cycle $\leq 2\%$.

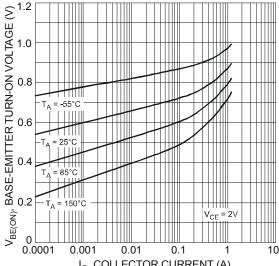




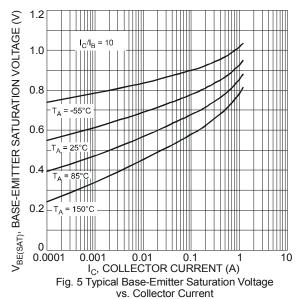




DXT5616U



I_C, COLLECTOR CURRENT (A)
Fig. 3 Typical Base-Emitter Turn-On Voltage
vs. Collector Current



300 f_T , GAIN-BANDWIDTH PRODUCT (MHz) 250 200 150 100 V_{CE} = 5V 50 f = 100MHz 0 _ 100 20 40 60 I_C, COLLECTOR CURRENT (mA) Fig. 7 Typical Gain-Bandwidth Product

vs. Collector Current

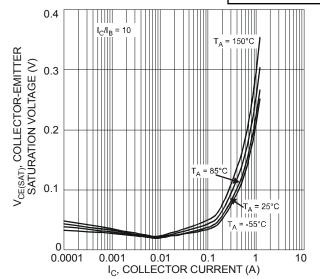


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

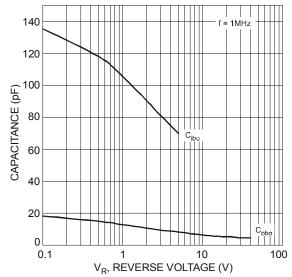
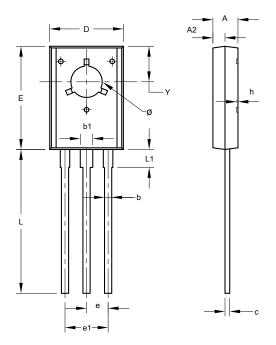


Fig. 6 Typical Capacitance Characteristics



Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



TO126					
Dim	Min	Max	Тур		
Α	2.400	2.900	-		
A2	1.060	1.500	-		
b	0.660	0.860	-		
b1	1.170	1.470	-		
С	0.400	0.600	-		
D	7.400	8.200	-		
Е	10.60	11.20	-		
е		-	2.280		
e1	ı	-	4.560		
h	0.00	0.30	-		
L	14.50	15.90	-		
L1	1.700	2.100	-		
Υ	3.600	3.900	-		
Ø	3.100	3.550	-		
All Dimensions in mm					





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